August 1997 Revised October 2002

74VCX162244

Low Voltage 16-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26 Ω Series Resistor in Outputs

General Description

The VCX162244 contains sixteen non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/ receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX162244 is designed for low voltage (1.2V to 3.6V) V_{CC} applications with I/O capability up to 3.6V. The 74VCX162244 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- \blacksquare 1.2V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- \blacksquare 26 Ω series resistors in outputs
- t_{PD}

3.3 ns max for 3.0V to 3.6V V_{CC}

- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal
- Static Drive (I_{OH}/I_{OL}) ±12 mA @ 3.0V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:

Human body model > 2000V Machine model > 200V

■ Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Note 1: To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

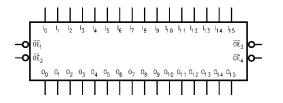
Ordering Code:

Order Number	Package Number	Package Description
74VCX162244G (Note 2)(Note 3)	BGA54A	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
74VCX162244MTD (Note 3)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: Ordering Code "G" indicates Trays.

Note 3: Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

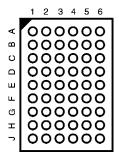
Logic Symbol



Connection Diagrams



Pin Assignment for FBGA



(Top Thru View)

Pin Descriptions

Pin Names	Description
\overline{OE}_n	Output Enable Input (Active LOW)
I ₀ -I ₁₅	Inputs
O ₀ -O ₁₅	Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	O ₀	NC	OE ₁	OE ₂	NC	I ₀
В	O ₂	O ₁	NC	NC	I ₁	l ₂
С	O ₄	O ₃	V _{CC}	V _{CC}	I ₃	I ₄
D	O ₆	O ₅	GND	GND	I ₅	I ₆
E	O ₈	O ₇	GND	GND	I ₇	I ₈
F	O ₁₀	O ₉	GND	GND	l ₉	I ₁₀
G	O ₁₂	O ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
Н	O ₁₄	O ₁₃	NC	NC	I ₁₃	I ₁₄
J	O ₁₅	NC	OE ₄	OE ₃	NC	I ₁₅

Truth Tables

Inputs		Outputs
OE ₁	I ₀ –I ₃	O ₀ -O ₃
L	L	L
L	Н	Н
Н	Χ	Z

Inputs		Outputs
OE ₂	I ₄ –I ₇	04-07
L	L	L
L	Н	Н
Н	X	Z

Inputs		Outputs
OE ₃ I ₈ -I ₁₁		O ₈ -O ₁₁
L	L	L
L	Н	Н
Н	Х	Z

Inp	outs	Outputs
ŌE₄	I ₁₂ -I ₁₅	O ₁₂ -O ₁₅
L	L	L
L	Н	Н
н	X	Z

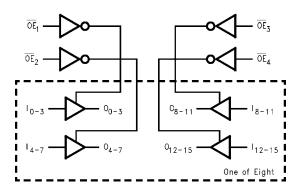
L = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial (HIGH or LOW, inputs may not float)
Z = High Impedance

Functional Description

The 74VCX162244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE out-

puts are controlled by an Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW, the outputs are in the 2-state mode. When \overline{OE}_n is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram



Absolute Maximum Ratings(Note 4)

Supply Voltage (V_{CC}) -0.5V to +4.6V DC Input Voltage (V_I) -0.5V to +4.6V Output Voltage (V_O)

Outputs 3-STATE -0.5V to +4.6VOutputs Active (Note 5) -0.5V to V_{CC} +0.5V DC Input Diode Current $(I_{IK}) V_I < 0V$ -50 mA

DC Output Diode Current (I_{OK})

 $V_O < 0V$ -50 mA $V_{O} > V_{CC}$ +50 mA

DC Output Source/Sink Current

 (I_{OH}/I_{OL}) ±50 mA DC V_{CC} or GND Current per

Supply Pin (I_{CC} or GND) ±100 mA Storage Temperature Range (T_{STG})

 $-65^{\circ}C$ to $+150^{\circ}C$

Recommended Operating Conditions (Note 6)

Power Supply

Operating 1.2V to 3.6V Data Retention Only 1.2V to 3.6V Input Voltage -0.3V to +3.6V

Output Voltage (V_O)

Output in Active States 0V to V_{CC}

Output in 3-State 0.0V to 3.6V

Output Current in I_{OH}/I_{OL}

 $V_{CC} = 3.0V$ to 3.6V±12 mA $V_{CC} = 2.3V \text{ to } 2.7V$ ±8 mA $V_{CC} = 1.65V \text{ to } 2.3V$ ±3 mA $V_{CC} = 1.4V \text{ to } 1.6V$ $\pm 2~\text{mA}$

 $V_{CC} = 1.2V$ ±100 μA Free Air Operating Temperature (T_A) -40°C to +85°C

Minimum Input Edge Rate ($\Delta t/\Delta V$)

 $V_{\mbox{\footnotesize{IN}}} = 0.8 \mbox{\footnotesize{V}}$ to 2.0 V, $V_{\mbox{\footnotesize{CC}}} = 3.0 \mbox{\footnotesize{V}}$

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < V_{CC} ≤ 3.6V)

Symbol	Parameter	Conditions	v _{cc}	Min	Max	Units
			(V)			
V _{IH}	HIGH Level Input Voltage		2.7 - 3.6	2.0		
			2.3 - 2.7	1.6		
			1.65 - 2.3	0.65 x V _{CC}		V
			1.4 - 1.6	0.65 x V _{CC}		
			1.2	0.65 x V _{CC}		
V _{IL}	LOW Level Input Voltage		2.7 - 3.6		0.8	
			2.3 - 2.7		0.7	
			1.65 - 2.3		$0.35 \times V_{CC}$	V
			1.4 - 1.6		$0.35 \times V_{\rm CC}$	
			1.2		0.5 x V _{CC}	
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.7 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	2.7	2.2		
		$I_{OH} = -8 \text{ mA}$	3.0	2.4		
		$I_{OH} = -12 \text{ mA}$	3.0	2.2		
		$I_{OH} = -100 \mu A$	2.7 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -4 \text{ mA}$	2.3	2.0		
		$I_{OH} = -6 \text{ mA}$	2.3	1.8		V
		$I_{OH} = -8 \text{ mA}$	2.3	1.7		
		$I_{OH} = -100 \mu A$	1.65 - 2.3	V _{CC} - 0.2		
		$I_{OH} = -3 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \mu A$	1.4 - 1.6	V _{CC} - 0.2		
		$I_{OH} = -1 \text{ mA}$	1.4	1.05		
		$I_{OH} = -100 \mu A$	1.2	V _{CC} - 0.1		
				•		

DC Electrical Characteristics (2.7V < VCC £ 3.6V) (Continued)

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7 - 3.6		0.2	
		I _{OL} = 6 mA	2.7		0.4	
		I _{OL} = 8 mA	3.0		0.55	
		I _{OL} = 12 mA	3.0		0.8	
		$I_{OL} = 100 \mu A$	2.7 - 3.6		0.2	
		I _{OL} = 6 mA	2.3		0.4	V
		I _{OL} = 8 mA	2.3		0.6	v
		$I_{OL} = 100 \mu A$	1.65 - 2.3		0.2	
		I _{OL} = 3 mA	1.65		0.3	
		$I_{OL} = 100 \mu A$	1.4 - 1.6		0.2	
		I _{OL} = 1 mA	1.4		0.35	
		$I_{OL} = 100 \mu A$	1.2		0.1	
I _I	Input Leakage Current	0 ≤ V _I ≤ 3.6V	1.2 - 3.6		±5.0	μΑ
I _{OZ}	3-STATE Output Leakage	0 ≤ V _O ≤ 3.6V	1.2 - 3.6		±10	μА
		$V_I = V_{IH}$ or V_{IL}	1.2 - 3.0		±10	μΑ
I _{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μА
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	1.2 - 3.6		20	μΛ
		$V_{CC} \le (V_I, V_O) \le 3.6V \text{ (Note 7)}$	1.2 - 3.6		±20	μΑ
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μΑ

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	Conditions	V _{CC}	T _A = -40°	C to +85°C	Units	Figure
Зушьог	Farameter	Conditions	(V)	Min	Max	Units	Number
t _{PHL} ,	Propagation Delay	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	3.3		Figures
t _{PLH}			2.5 ± 0.2	1.0	3.8		1, 2
			1.8 ± 0.15	1.5	7.6	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	15.2		Figures
			1.2	1.5	38		5, 6
t _{PZL} ,	Output Enable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	3.8		
t _{PZH}			2.5 ± 0.2	1.0	5.1		Figures 1, 3, 4
			1.8 ± 0.15	1.5	9.8	ns	1, 2,
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	19.6		Figures
			1.2	1.5	49		5, 7, 8
t _{PLZ} ,	Output Disable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	3.6		
t_{PHZ}			2.5 ± 0.2	1.0	4.0		Figures 1, 3, 4
			1.8 ± 0.15	1.5	7.2	ns	1, 2, 1
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	14.4		Figures
			1.2	1.5	36		5, 7, 8
toshl	Output to Output Skew	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3		0.5		
t _{OSLH}	(Note 9)		2.5 ± 0.2		0.5		
			1.8 ± 0.15		0.75	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1		1.5		
			1.2		1.5		

Note 8: For C_L = 50 $_P$ F, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

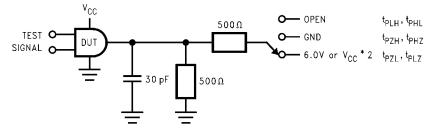
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC}	$T_A = +25^{\circ}C$	Units
Symbol		Conditions	(V)	Typical	Ointo
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.15	
			2.5	0.25	V
			3.3	0.35	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.15	
			2.5	-0.25	V
			3.3	-0.35	
V _{OHV}	Quiet Output Dynamic Valley V _{OH}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.55	
			2.5	2.05	V
			3.3	2.65	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25^{\circ}C$	Units
Cymbol	i arameter	Conditions	Typical	Oillo
C _{IN}	Input Capacitance	$V_{CC} = 1.8, 2.5 V \text{ or } 3.3 V, V_I = 0 V \text{ or } V_{CC}$	6	pF
C _{OUT}	Output Capacitance	$V_I = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7	pF
C _{PD}	Power Dissipation Capacitance	$V_I = 0V \text{ or } V_{CC}, f = 10 \text{ MHz}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	20	pF

AC Loading and Waveforms (V $_{CC}$ 3.3V \pm 0.3V to 1.8V \pm 0.15V)



TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V at $V_{CC} = 3.3 \pm 0.3V$; $V_{CC} \times 2$ at $V_{CC} = 2.5 \pm 0.2V$; 1.8 $\pm 0.15V$
t _{PZH} , t _{PHZ}	GND

FIGURE 1. AC Test Circuit

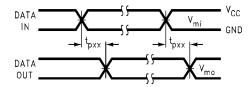


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

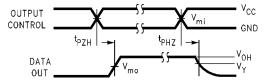


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

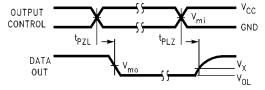
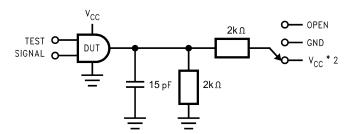


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V _{CC}			
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V	
V _{mi}	1.5V	V _{CC} /2	V _{CC} /2	
V _{mo}	1.5V	V _{CC} /2	V _{CC} /2	
V _X	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V	
V _Y	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V	

AC Loading and Waveforms (V_{CC} 1.5V \pm 0.1V to 1.2V)



	TEST	SWITCH
t _l	PLH, t _{PHL}	Open
t	_{PZL} , t _{PLZ}	V_{CC} x 2 at V_{CC} = 1.5V \pm 0.1V
t	_{PZH} , t _{PHZ}	GND

 $\mathsf{t}_{\mathsf{PLH}},\,\mathsf{t}_{\mathsf{PHL}}$

 t_{PZH} , t_{PHZ}

 t_{PZL} , t_{PLZ}

FIGURE 5. AC Test Circuit

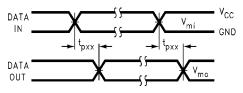


FIGURE 6. Waveform for Inverting and Non-Inverting Functions

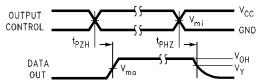


FIGURE 7. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

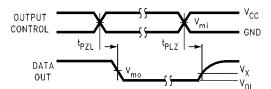
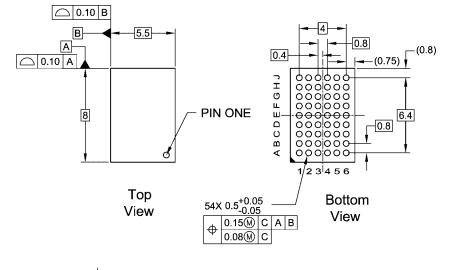
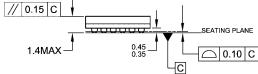


FIGURE 8. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V _{CC}	
- Cymber	1.5V ± 0.1V	
V _{mi}	V _{CC} /2	
V_{mo}	V _{CC} /2	
V _X	V _{OL} + 0.1V	
V_{Y}	V _{OL} – 0.1V	

Physical Dimensions inches (millimeters) unless otherwise noted



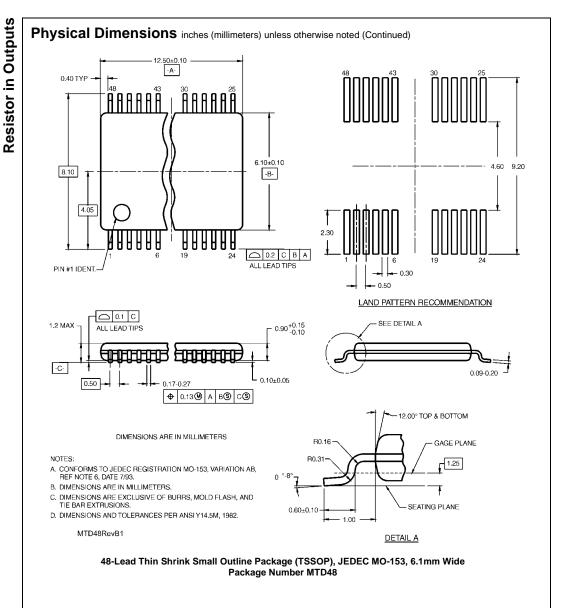


NOTES:

- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
- **B. ALL DIMENSIONS IN MILLIMETERS**
- C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)
 .35MM DIA PADS WITH A SOLDERMASK OPENING OF .45MM CONCENTRIC TO PADS
 D. DRAWING CONFORMS TO ASME Y14.5M-1994

BGA54ArevD

54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide Package Number BGA54A



Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com